

PERIODIC GENERATION AND PROPAGATION OF TRAVELING FRONTS IN DC VOLTAGE BIASED SEMICONDUCTOR SUPERLATTICES*

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Abstract. The continuum limit of a recently proposed model for charge transport in resonant-tunneling semiconductor superlattices (SLs) is analyzed. It is described by a nonlinear hyperbolic integrodifferential equation on a one-dimensional spatial support, supplemented by shock and entropy conditions. For appropriate parameter values, a time-periodic solution is found in numerical simulations of the model. An asymptotic theory shows that the time-periodic solution is due to recycling and motion of shock waves representing domain walls connecting regions of the SL where the electric field is almost uniform.

Key words. shock wave dynamics, semiconductor instabilities, multiscale methods

AMS subject classifications. 35G25, 35M05, 35B25

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1. Introduction. Self-sustained oscillations of the current have been observed in recent experiments on n-doped weakly coupled semiconductor SLs under *dc*-voltage bias along the growth direction [16]. The main charge transport mechanism is quantum resonant tunneling through the SL [11, 17, 12, 21, 22, 23]. Similar but damped oscillations have been reported earlier in undoped SLs subject to laser photoexcitation [20]. In both cases a phenomenological discrete drift model proposed by one of the authors [6] explains the oscillations in terms of the formation and dynamics of electric field domains, i.e., regions in space in which the strength of the electric field is nearly uniform. These phenomena are thus examples of time-dependent pattern formation in resonant-tunneling SLs, a scarcely explored area of semiconductor physics.

We shall study asymptotically and numerically the self-sustained oscillatory solutions of the continuum limit of the model that applies when the number of quantum wells in the SL is large or, equivalently, when the SL is long. The continuum limit of the model, to be derived below, is given by the equations (see [4])

$$(1.1) \quad \frac{\partial E}{\partial t} + v(E) \left(1 + \frac{\partial E}{\partial x} \right) = I,$$

$$(1.2) \quad \frac{1}{L} \int_0^L E(x, t) dx = \phi.$$

The unknowns in these equations are the current density $I(t)$ and the electric field $E(x, t)$ on a one-dimensional SL $0 < x < L$. The velocity $v(E)$, shown in the inset

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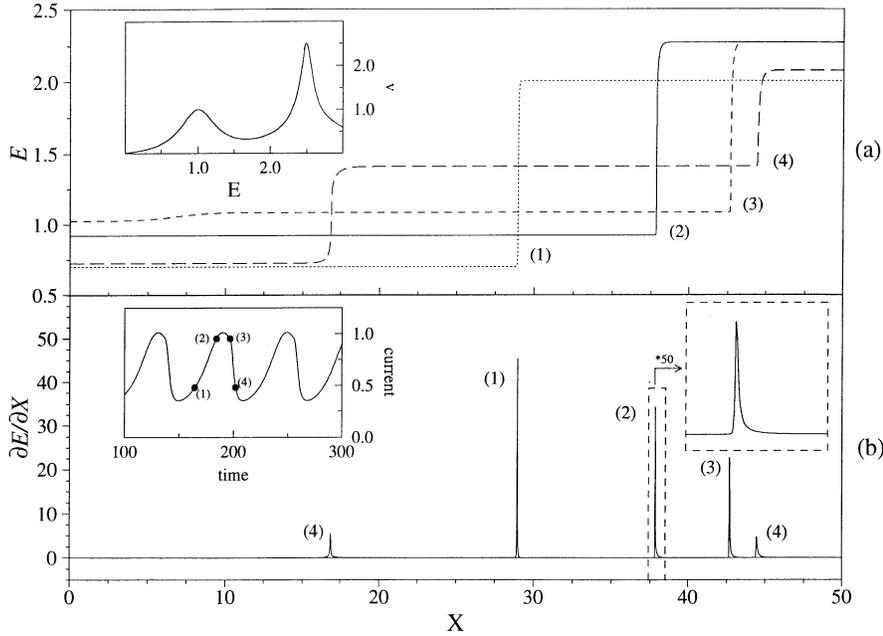


FIG. 1. (a) Time evolution of the electric field profile on the SL using the velocity curve shown in the inset. (b) Charge density profiles, $\partial E(x,t)/\partial x$, showing the location of the IL for different times. The total current density versus time is shown in the leftmost inset, in which we have marked the times corresponding to the profiles depicted in part (a). The rightmost inset shows clearly a monopole with a right tail.

of Figure 1a, is a positive function for $E > 0$ having two peaks at $E = 1$ [$v(1) = 1$] and $E = E_M > 1$ [$v(E_M) = v_M > 1$] separated by a minimum at $E = E_m \in (1, E_M)$ [$v(E_m) = v_m < 1$]. The constant ϕ is a control parameter proportional to the dc-voltage bias. The self-sustained oscillations are stable time-periodic solutions that appear for $1 < \phi < E_m$; see the oscillation of the current density in the inset of Figure 1b. Equations (1.1) and (1.2) are to be solved with the boundary condition [4]:

$$(1.3) \quad \frac{\partial E(0,t)}{\partial x} = c > 0.$$

Equation (1.1) is hyperbolic, so its solutions will in general develop shock waves. We supplement the model with the shock condition [4]

$$(1.4) \quad \int_{E_-}^{E_+} \left(\frac{1}{v(E)} - \frac{1}{V(E_+, E_-)} \right) dE = 0$$

and the entropy condition [4]

$$(1.5) \quad v(E_-) \geq V(E_+, E_-) \geq v(E_+).$$

Here $V(E_+, E_-)$ is the velocity of a shock wave located at $x = X(t)$ and such that $E(X-, t) = E_-$ and $E(X+, t) = E_+$.

Physically, (1.2) expresses the fact that the voltage drop across the semiconductor length is kept constant at the value ϕL . Equation (1.1) can be derived directly from

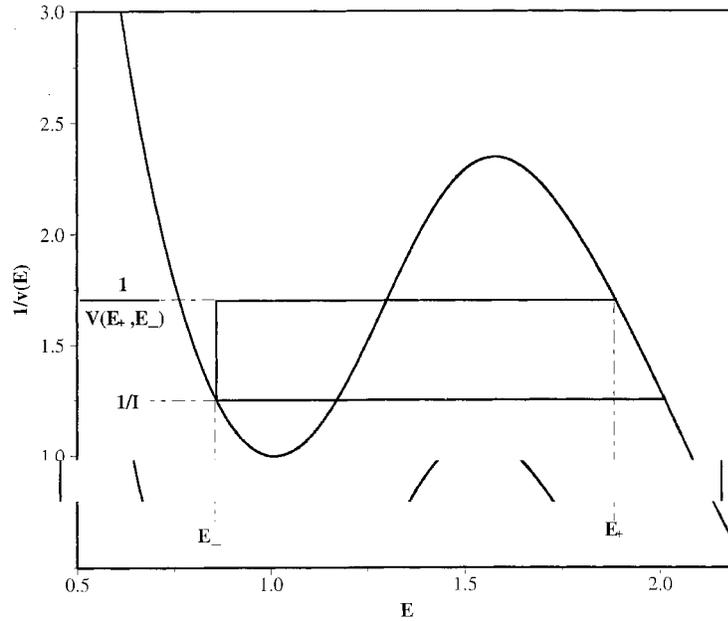


FIG. 2. Equal-area rule relating the electric field values behind, E_- , and in front, E_+ , of the shock wave with its velocity $V(E_+, E_-)$.

Ampere's law

$$(1.6) \quad \frac{\partial E}{\partial t} + v(E)n = I,$$

by substituting in it the Poisson equation

$$(1.7) \quad \frac{\partial E}{\partial x} = n - 1,$$

where the one in the right-hand side represents the normalized density of the dopant. The electron current $v(E)n$ is essentially given by the probability of tunneling from one quantum well of the SL to the next one and is assumed to be proportional to the electron density in the quantum well. Our derivation of (1.1) homogenizes over the SL structure. The quantum effects due to the SL structure that dominates the phenomenon are modeled in the shape of the function $v(E)$ (the electron velocity) and in particular in its having two peaks as shown in the inset of Figure 1a above. Peaks occur at certain values of the field as a result of energy level alignment in adjacent quantum wells that leads to enhanced (or resonant) tunneling and hence to enhanced transmission.

The shock condition (1.4) arises in the passage from the discrete model to the continuum model. It has the geometric interpretation of an equal area rule as one observes in Figure 2. In essence the shock condition provides a relation between the field E_+ at the front of the shock wave, the field E_- at the back of the shock, and the shock speed V . The domain of this relation is restricted by the requirement that the entropy condition be satisfied. The entropy condition (1.5) is the usual one, saying that the particles entering the shock move faster than the shock itself, which in turn moves faster than the particles it encounters. The entropy condition also ensures that

the electron density inside the shock wave (see below for the meaning of a region of the SL inside of the shock wave) is positive.

Our calculation is organized as follows: in section 2 we discuss the oscillations from a qualitative viewpoint and in the further sections we do the analysis of one complete cycle of the oscillations. We start by analyzing the shock kinematics, in section 3, and explaining analytically the numerically observed monopole (shock plus tail) structure. In section 4 we introduce our asymptotic scaling, derive the outer and inner solutions, and put the pieces together working and matching in sequence the different regions which describe a whole oscillation cycle. In sections 5 and 6 we analyze in detail the process of creation and disappearance of a monopole, and in section 7 we include some final remarks. Finally, Appendix A contains a derivation of the continuum limit of the discrete SL model.

2. Qualitative discussion of current oscillations. We study the asymptotic limit in which the length of the SL sample is large. We have derived the time-periodic solution of the above model asymptotically and numerically. We describe it in Figure 1, in which the numerical solution of equations (1.1)–(1.3) is represented. This numerical solution has been obtained by the method of lines, using backward differences in space, a fourth-order Runge–Kutta method in time, and a large number of grid points (5000) in order to have sufficient precision in the numerical approximation. Notice that this method is, in fact, equivalent to solving the discrete model (A.7)–(A.10) as an initial value problem. We have also solved equations (1.1)–(1.3) using a fully implicit finite difference scheme and including an artificial diffusion term proportional to $v(E)$. The key element of this method is a modification of the method proposed in [1], which distributes the grid points according to a monitor function sensitive to the local values of the slope of the field distribution and is tuned to track the travelling internal layers (ILs). The results obtained with both methods agree.

One observes that at all times the field is essentially uniform over two or three spatial intervals called domains. The latter are separated by one or, respectively, two thin ILs in which the field value experiences a positive jump. The IL(s) are monotonically increasing in x . To follow a complete cycle, we start with two domains separated by a single IL. Before the IL has reached the end of the sample $x = L$, a second IL starts forming at an interior point to the left of the first one and also moves to the right. The field now displays two ILs separating three domains. As time still increases, the IL on the right disappears either because it reaches the right end $x = L$ of the sample (for $1 \leq \phi < \phi_d$) or because the jump between the field values to its left and to its right decreases to zero (for $\phi > \phi_d$, where $1 < \phi_d < E_m$). This leaves a field profile that has only two domains. The cycle then repeats itself. Throughout the cycle, the uniform value of the field in each domain varies continuously and periodically with time. At each time, the field is an increasing function of the spatial variable. See Figure 1.

In each IL, we find that a shock connects the left or right value of the field with an intermediate field value. The latter, in turn, connects to the value on the other side of the IL by an exponential tail that moves rigidly with the shock. The characteristics are parallel to the shock line on the side of the tail and end in the shock line transversely on the other side. We call the combination of a shock and a tail a “monopole wavefront.” In this language, an IL is a monopole wavefront that consists of a shock and a right tail or a shock and a left tail. As we explain in section 3, the structure of a shock with a left AND right tail does not appear.

As the field displays the time-periodic spatial pattern formation described above, the current performs a simple oscillation as seen in the inset of Figure 1b. Roughly speaking, it increases with time as long as there are only two field domains and decreases when there are three field domains. We can describe how the field values on the domains depend on the current without reference to the position of the shocks in the following way. In the asymptotic scaling of interest (see (4.1)–(4.4) below), in which the length of the semiconductor sample and the speed of the shocks are of order $O(1)$, the quasi-static approximation $I = v(E)$ is valid as long as the current value is between the local maximum and the local minimum of the v curve (see the inset of Figure 1a) and not too close to these extreme values. The three roots of the equation above are denoted by $E^{(1)}(I) < E^{(2)}(I) < E^{(3)}(I)$. As the current increases (Region I, times (1) and (2) in Figure 1) taking values in the interval $(v_m, 1)$, there are only two domains separated by an IL. The field on the left domain takes the value $E^{(1)}(I)$, while on the right domain it takes the value $E^{(3)}(I)$. The shock condition and the entropy condition, plus the requirement that monopoles can have only a left OR (exclusive) right tail, allow us to determine uniquely the shock and tail characteristics as functions of the current. After the current reaches its maximal value, a value that, as we will see, is a little higher than the peak of the v curve, a new shock is created (Region II, time (3) in Figure 1). As the current value now decreases (Region III, time (4) in Figure 1), there are three field domains. The field value on the left domain is $E^{(1)}(I)$, the value on the middle domain is $E^{(2)}(I)$, and on the right domain it is $E^{(3)}(I)$. Again, using the shock and entropy conditions, we can determine uniquely the characteristics of the two shocks and tails. This determination is shown graphically in the five pictures in Figure 3 that describe the whole cycle. We are forced to graph $1/v$ instead of the more natural v in this figure, because v appears in the denominator of the shock condition. Thus, for example, instead of picturing the current increasing, we think of $1/I$ decreasing. The monopole on the right disappears (Region IV is not shown in the figures) as the current is close to its minimal value, a value that is equal or slightly higher than the minimum of the v curve, depending on the bias.

The position of the IL in Region II is directly determined from the voltage bias condition as a function of I . Since the shock position and speed are known functions of the current, we easily obtain an ODE for the current as a function of time from which the time dependence of the current and of the shock position may be derived. A similar but more involved calculation holds in Region III, where the current decreases taking values in the interval $(v_m, 1)$. We have three relations: a formula for each of the two shock speeds as functions of the current and the voltage bias condition. The latter is a linear relation between the positions of the two shocks in which the coefficients are known functions of the current. We have three unknowns: the two IL positions and the current. We can determine the unknowns as functions of time given appropriate initial conditions. We provide the required initial conditions by (a) calculating the time and position of shock formation and (b) matching with the field in Region II, in which the current is near its peak value. In Regions II and IV the quasi-stationary approximation is not always valid. We use fast scale variables to describe the birth and death of a shock in detail and match them to Regions I and III.

We can represent the evolution of the shock wave without considering its spatial trajectory on the SL by means of the following diagram. We define the function $E_+ = \mathcal{F}(E_-, u)$ (where $u = 1/V$) by solving the equal area rule (1.4) for E_+ . This function yields the field in front of the shock wave, given appropriate values of the shock speed and of the field at the back of the shock. The *domain* of this function

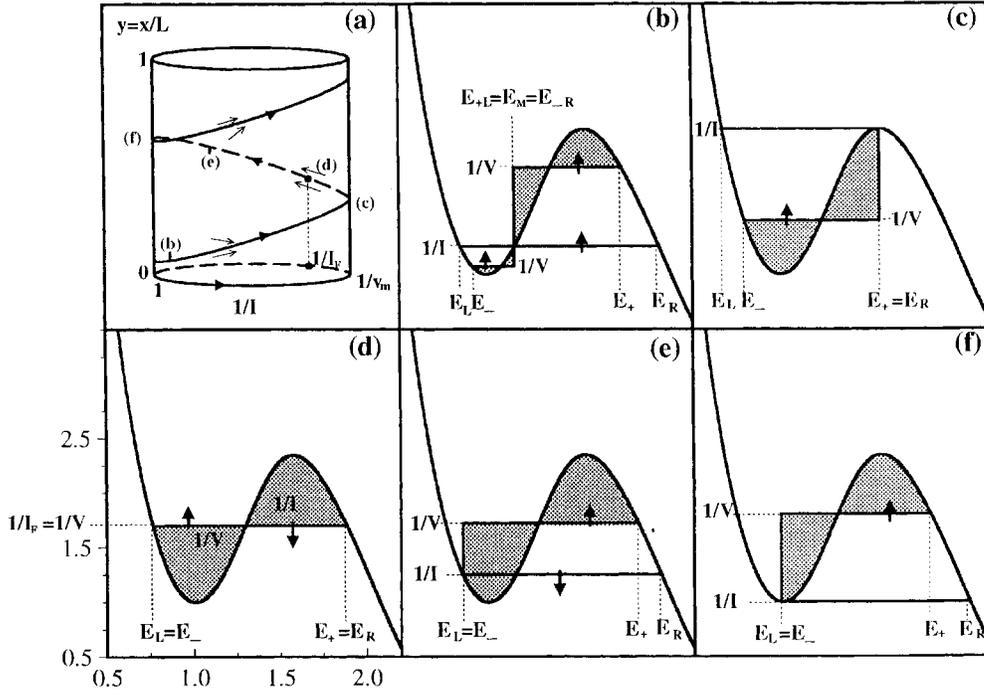


FIG. 3. The time-periodic solution in a nutshell. (a) Motion of one shock during one period on a cylindrical surface whose axis is space. The diameter of the cylinder basis is $1 < 1/I < 1/v_m$. (b) to (f) highlight of the equal-area conditions for the shock waves appearing in the electric field profile. They correspond to the different stages marked in Figure 1b.

consists of all the points $(E_-, 1/V)$ for which there is an E_+ such that the equal area rule and the entropy inequalities are true. Thus a point in the domain characterizes a shock completely. In Figure 4 we have depicted the domain of $\mathcal{F}(E_-, u)$ and the complete lifecycle of a shock wave in it. As one can see in the figure and easily derive, the domain of $\mathcal{F}(E_-, u)$ is bounded below by the graph of the function $1/v(E)$. It is bounded above by a line on which E_+ reaches the maximal value obtained by the equal area rule that does not violate the entropy inequalities $v(E_+) = V(E_+, E_-)$. This line intersects the graph of $1/v(E)$ at point $(E_F, 1/I_F)$ on the first branch. It again intersects the graph at the common point of the second and third branches $(E_m, 1/v_m)$. Observe that on the part of the first branch that belongs to the domain, we have $v(E_-) = V(E_+, E_-)$, while on the second branch we have $E_+ = E_-$. Also observe that $E_- = E^{(1)}(I_F)$ and $E_+ = E^{(3)}(I_F)$.

According to both our numerical experiments and asymptotic calculation, the shock wave moves so that the point $(E_-, 1/V)$ always remains on the boundary of the domain of $\mathcal{F}(E_-, u)$. The shock wave first appears at a point on the second branch of $1/v(E)$ where $E_+ = E_-$ (see Figure 4). Then the point $(E_-, 1/V)$ moves from the second to the first branch of $1/v(E)$, where it satisfies $V(E_+, E_-) = v(E_-)$ until it arrives at $(E_F, 1/I_F)$. It then continues moving on the upper boundary of the domain of $\mathcal{F}(E_-, u)$ where $V(E_+, E_-) = v(E_+)$, until it reaches $(E_m, 1/v_m)$ where the shock wave dies. (We have assumed a large enough bias, $\phi > \phi_d$. For smaller biases, the shock reaches $x = L$ before the current has attained its minimum value. Then the shock dies at some point on the upper boundary of the domain of $\mathcal{F}(E_-, u)$.)

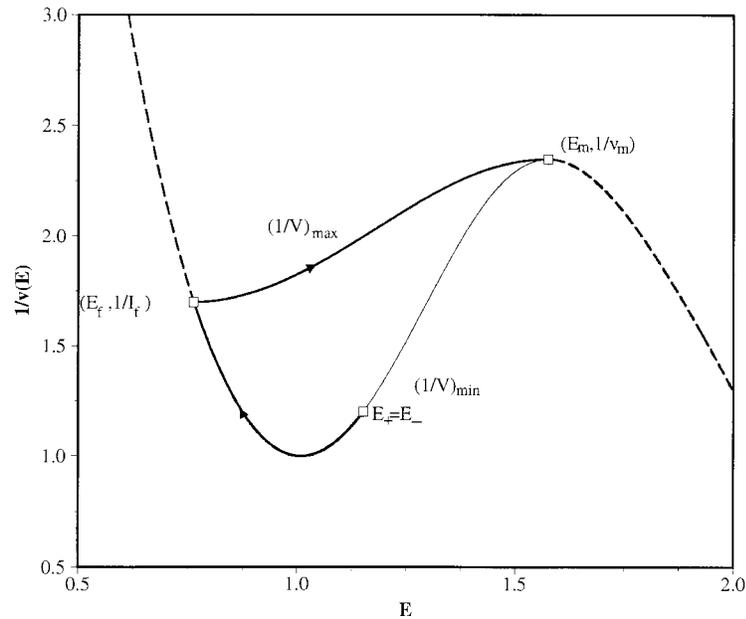


FIG. 4. Domain of the function $E_+ = \mathcal{F}(E_-, 1/V)$. The projection of $E_+(t)$ on this diagram for each time represents the evolution of the shock wave during its entire life.

To summarize, in a full cycle of the oscillation the following regions can be identified:

- *Region I.* One monopole (two domains) exists, and the current is increasing (see Figure 3e).
- *Region II.* A second monopole is born near $x = 0$, and the current is nearing a maximum which is slightly higher than the peak of the v curve (see Figure 3f).
- *Region III.* Two monopoles (three domains) propagate, and the current decreases (see Figure 3b).
- *Region IV.* The monopole on the right disappears, and the current is nearing a minimum which is slightly higher than the minimum of the v curve (see Figure 3c).

The different regions described here are analyzed asymptotically in section 4, where we derive the outer and inner solutions and put the pieces together working and matching in sequence on Regions I, II, III, and IV. The technical work on Regions II and IV is done in sections 5 and 6, respectively.

3. Kinematics of shock waves. In this section we shall analyze the processes of shock formation (near the boundary) and the existence and properties of monopole wavefronts which are a shock wave and a tail to its left or right moving at the shock velocity. These matters are fundamental ingredients of the asymptotics of later sections.

3.1. Formation of shock waves. The formation of shock waves on the infinite real line from arbitrary initial data and constant current have been considered before for the model of the Gunn effect in semiconductors [18, 24, 2]. The main result is that for an initial positive field profile a shock wave develops in finite time if $\partial E/\partial x > 0$

is large enough. For the time-periodic solution we are interested in, the shock waves develop near the boundary at $x = 0$ for appropriate values of the current density. We shall now analyze Region II and derive exact formulas for the time and position at which a new shock wave appears.

Let us solve the hyperbolic equation (1.1) with the boundary condition (1.3) by the method of characteristics:

$$(3.1) \quad \frac{dE(t; \tau)}{dt} = I - v(E(t; \tau)),$$

$$(3.2) \quad \frac{dx(t; \tau)}{dt} = v(E(t; \tau)),$$

with the boundary conditions

$$(3.3) \quad E(\tau; \tau) = E_0(\tau),$$

$$(3.4) \quad x(\tau; \tau) = 0.$$

We have parametrized the characteristic curves by the times at which they issue from the boundary at $x = 0$. The boundary field $E_0(\tau)$ has to be chosen so that the boundary condition $\partial E(0, t)/\partial x = c$ holds. Clearly,

$$(3.5) \quad c = \frac{\partial E}{\partial x}(0, t) = \frac{\partial E}{\partial \tau}(\tau; \tau) \frac{\partial \tau}{\partial x} \Big|_{x=0}.$$

We derive some relations that will be of use. Taking a τ -derivative of the solution of (3.2) and (3.4)

$$(3.6) \quad x(t; \tau) = \int_{\tau}^t v(E(s; \tau)) ds,$$

and then setting $x = 0$ (equivalently, $t = \tau$) in the result, we obtain

$$(3.7) \quad \frac{\partial x}{\partial \tau}(\tau; \tau) = -v(E(\tau; \tau)) = -v(E_0(\tau)).$$

Equations (3.5) and (3.7) yield

$$(3.8) \quad \frac{\partial E}{\partial \tau}(\tau; \tau) = -cv(E_0(\tau)).$$

An equation for E_0 is found by taking a τ -derivative of the boundary condition (3.3) and substituting (3.8) in the result:

$$\frac{dE_0}{d\tau} = \frac{\partial E}{\partial t}(\tau; \tau) + \frac{\partial E}{\partial \tau}(\tau; \tau) = I(\tau) - v(E_0(\tau)) - cv(E_0(\tau));$$

that is,

$$(3.9) \quad \frac{dE_0(\tau)}{d\tau} + (c+1)v(E_0(\tau)) = I(\tau).$$

This equation may be obtained directly by substituting $c = \partial E/\partial x$ into the hyperbolic equation (1.1). Finally, we can combine (3.1) and (3.2) into the equation

$$(3.10) \quad x(t; \tau) + E(t; \tau) = \int_{\tau}^t I(s) ds + E_0(\tau).$$

We can now derive a formula for the time at which a shock wave first appears. This happens when the function $\tau(x; t)$, obtained by solving $x(t; \tau) = x$ for fixed t , first becomes multivalued. At the time of shock formation, the function $x(t; \tau)$ has an inflection point with zero slope in the τ variable and therefore satisfies $\partial x(t; \tau)/\partial \tau = 0$ and $\partial^2 x(t; \tau)/\partial \tau^2 = 0$. These are two conditions to be used in determining the time and location of the new shock wave

$$(3.11) \quad \frac{\partial x(t; \tau)}{\partial \tau} = \frac{dE_0}{d\tau} - I(\tau) - \frac{\partial E(t; \tau)}{\partial \tau} = -(1 + c)v(E_0(\tau)) - \frac{\partial E(t; \tau)}{\partial \tau},$$

where (3.9) has been used. We can find $\partial E(t; \tau)/\partial \tau \equiv E_\tau(t; \tau)$ by differentiating (3.1) and (3.3) with respect to τ , using (3.8), and solving the resulting linear problem

$$(3.12) \quad \frac{dE_\tau(t; \tau)}{dt} = -v'(E(t; \tau)) E_\tau(t; \tau),$$

$$(3.13) \quad E_\tau(\tau; \tau) = -cv(E_0(\tau)).$$

The result may be inserted into (3.11) to obtain

$$(3.14) \quad \frac{\partial x(t; \tau)}{\partial \tau} = v(E_0(\tau)) \left(c \exp \left[- \int_\tau^t v'(E(s; \tau)) ds \right] - 1 - c \right).$$

From (3.14) we immediately obtain

$$(3.15) \quad \frac{\partial^2 x(t; \tau)}{\partial \tau^2} = \frac{v'(E_0(\tau))}{v(E_0(\tau))} E'_0(\tau) \frac{\partial x(t; \tau)}{\partial \tau} + cv(E_0(\tau)) \exp \left[- \int_\tau^t v'(E(s; \tau)) ds \right] \times \left(v'(E_0(\tau)) + cv(E_0(\tau)) \int_\tau^t v''(E(r, \tau)) \exp \left[- \int_\tau^r v'(E(s; \tau)) ds \right] dr \right).$$

When the expressions given by (3.14) and (3.15) are set equal to zero, their solutions $t = t_s$ and $\tau = \tau_s$ yield the time and position at which a shock wave first appears:

$$(3.16) \quad \frac{c}{1 + c} = \exp \left[\int_{\tau_s}^{t_s} v'(E(t; \tau_s)) dt \right],$$

$$(3.17) \quad -\frac{v'(E_0(\tau_s))}{cv(E_0(\tau_s))} = \int_{\tau_s}^{t_s} v''(E(r, \tau_s)) \exp \left[- \int_{\tau_s}^r v'(E(s; \tau_s)) ds \right] dr,$$

$$(3.18) \quad x_s = \int_{\tau_s}^{t_s} v(E(t; \tau_s)) dt.$$

The times t_s and τ_s in (3.16) and (3.18) are functions of c and L determined by the condition that t_s is the smallest time for which (3.16) and (3.17) are satisfied. Notice that (3.16) has no solution $t_s > \tau_s$ for $-1 \leq c \leq 0$. This explains why the time-periodic electric field profiles, which appear in the numerical simulations with such boundary conditions, do not exhibit shocks [15]. In order to find t_s, x_s , and τ_s from equations (3.16)–(3.18), we need to know $E(t; \tau)$ along the characteristics, which is obtained by solving (3.1) when the current is known. This analysis is carried out in section 4.3 using an asymptotic approximation to the current density $I(t)$.

3.2. Monopole wavefronts. We now construct the ILs referred to in the Introduction, which are basic elements of our asymptotics. Assuming constant current, we construct shock waves with a left or right tail moving rigidly at the shock velocity

$V(E_+, E_-)$. We call a *monopole with a left (resp., right) tail* the IL composed of the shock wave plus the transition layer (the tail) to its left (resp., right). The monopoles will be used as building blocks in the asymptotic description of the time-periodic solution. In the moving coordinate $\chi = x - X(t)$, where $X(t)$ is the position of the shock at time t [so $dX/dt = V(E_+, E_-)$], we have

$$(3.19) \quad [v(E) - V(E_+, E_-)] \frac{\partial E}{\partial \chi} = I - v(E).$$

We shall distinguish two cases.

Case 1. $I < V$. We construct a left tail by solving (3.19) in the region $\chi \leq 0$. As χ varies from 0 to $\chi = -\infty$, E varies from $E(0-) = E_-$ to $E(-\infty) = E_L$. The quantity $v(E)$ varies from $v(E_-)$ to $v(E_L) = I$ (E_L is necessarily a fixed point of (3.19)). Let us prove that $v(E_-) = V(E_+, E_-)$. If $V < v(E_-)$, we have $v(E_L) = I < V < v(E_-)$, and the function $v(E) - V$ has a zero between E_L and E_- . Thus (3.19) does not have a solution that connects E_L and E_- , and we must have $v(E_-) \leq V(E_+, E_-)$. But then the entropy condition $V(E_+, E_-) \leq v(E_-)$ implies $V(E_+, E_-) = v(E_-)$. The behavior of the tail near $\chi = 0$ is described by

$$\frac{dE}{d\chi} \sim \frac{I - V}{v'(E_-(E - E_-))}, \quad E(0) = E_-,$$

which when solved yields

$$E(\chi) \sim E_- - \sqrt{\frac{2(V - I)}{v'(E_-)}} \sqrt{-\chi}, \quad \chi \rightarrow 0^-.$$

With this choice of the minus sign in front of the square root, $E(\chi)$ is an increasing function, as indicated by (3.19). Since $V > I$, $v'(E) > 0$, and therefore E_- is necessarily on the first branch of the v curve.

The only solution of (3.19) for $\chi > 0$ with $E(0+) = E_+$ that we have observed in the numerical simulations is the constant solution $E(\chi) = E_+$, with $v(E_+) = I$. We have the following partial explanation of this fact. Let $E(\chi) \rightarrow E_R$ as $\chi \rightarrow \infty$. Clearly $v(E_R) = I$. In a neighborhood of E_R we can multiply (3.19) by $v'(E) \sim v'(E_R)$ and obtain

$$\frac{d}{d\chi}(v - I) \sim \frac{v'(E_R)}{V - I}(v - I).$$

As $\chi \rightarrow \infty$, the point $v = I$ is unstable if $v'(E_R) > 0$ and stable if $v'(E_R) < 0$. The unstable case corresponds to fields on the third branch of the $v(E)$ curve, and the only solution having $E \rightarrow E_R$ (hence $v(E) \rightarrow v(E_R)$) as $\chi \rightarrow \infty$ is $E \equiv E_R = E_+$ ($v \equiv I$). In the stable case, we cannot exclude right tails based on the above arguments. We have excluded them because they do not appear in our numerical simulations.

Case 2. $I > V$. This case is completely analogous to Case 1. We obtain monopole waves with a right tail. To summarize, we note the following.

- When $I < V$, $v(E_-) = V(E_+, E_-) \equiv U(E_+)$, $I = v(E_+)$, the monopole moves with velocity $dX/dt = U(E_+)$, and it has a left tail, i.e., $E_L < E_- < E_+ = E_R$.
- When $I > V$, $v(E_+) = V(E_+, E_-) \equiv W(E_-)$, $I = v(E_-)$, the monopole moves with velocity $dX/dt = W(E_-)$, and it has a right tail, i.e., $E_L = E_- < E_+ < E_R$.

The functions $U(E_+)$ and $W(E_-)$ are defined by the above relations.

In Figure 1a a monopole with a right tail can be observed in the field profile corresponding to time (2). This is better displayed when plotting $\partial E/\partial x$ as shown in the inset of Figure 1b. Time (1) corresponds to a value of the current close to I_F ($I_F = 0.58$) where neither a left nor a right tail exists.

4. Asymptotic analysis of the time-periodic solution. Let us describe one period of the oscillations for bias $1 < \phi < E^{(3)}(1)$ (recall that $E^{(1)}(I) < E^{(2)}(I) < E^{(3)}(I)$ are the three roots of $v(E) - I$ for $v_m < I < 1$). It is convenient to redefine the time and space scales in such a way that the SL length becomes 1:

$$(4.1) \quad \epsilon = \frac{1}{L}, \quad y = \frac{x}{L}, \quad s = \frac{t}{L}.$$

Then (1.1)–(1.3) become

$$(4.2) \quad \frac{\partial E}{\partial s} + v(E) \frac{\partial E}{\partial y} = \frac{I - v(E)}{\epsilon},$$

$$(4.3) \quad \int_0^1 E(y, s) dy = \phi,$$

$$(4.4) \quad \frac{\partial E(0, s)}{\partial y} = cL.$$

We shall describe the time-periodic solution of these equations in the limit $\epsilon \rightarrow 0$ ($L \rightarrow \infty$) by leading-order matched asymptotic expansions. Observe that L is the nondimensional length of the SL (see Appendix A, equations (A.6) and (A.11)), and therefore we analyze the limit in which the SL length is large compared with $\epsilon \tilde{E}_M / (\tilde{N}_D e)$.

4.1. Outer solutions. Clearly the leading order of the outer expansion of the solutions to (4.2)–(4.3) yields

$$(4.5) \quad I - v(E) = 0.$$

Then the outer electric field is a piecewise constant function whose profile is a succession of zeros of $I - v(E)$, $E^{(k)}(I)$ ($k = 1, 2, 3$), separated by discontinuities. These discontinuities are the shock waves corresponding to monopoles with left or right tails moving with speeds given by (1.4), as discussed in section 3. Let us suppose that $y = Y(s)$ represents the location of a shock wave separating two different solutions of (4.5). According to section 3,

$$(4.6) \quad \frac{dY}{ds} = U(E_+), \quad V(E_+, E_-) = v(E_-) \equiv U(E_+) \quad \text{if } I < V(E_+, E_-),$$

$$(4.7) \quad \frac{dY}{ds} = W(E_-), \quad V(E_+, E_-) = v(E_+) \equiv W(E_-) \quad \text{if } I > V(E_+, E_-).$$

Notice that the limiting values E_+ in (4.6) and E_- in (4.7) are solutions of (4.5), and therefore they are functions of $I(s)$. The current density should then be determined from these equations and the bias condition (4.3) (see below).

4.2. Inner solutions. Near $y = 0$ or near the shock waves there are regions of fast variations of the electric field. In them $I = I(s)$, $E \sim F(x, t)$, where $x = y/\epsilon$ and $t = s/\epsilon$ according to (4.1).

The field in the boundary layer near $y = 0$ obeys the equations

$$(4.8) \quad \frac{\partial F}{\partial t} + v(F) \frac{\partial F}{\partial x} = I(s) - v(F),$$

$$(4.9) \quad F(0, t) = E_0(s), \quad \text{with} \quad \epsilon \frac{dE_0}{ds} + (1 + c) v(E_0) = I(s),$$

because of (3.9). Except in very short time intervals when a new shock wave is being formed, $F = F(x)$ is a quasi-stationary monotonically increasing profile joining $F(0) = E^{(1)}[I(s)/(1 + c)]$ and $F(\infty) = E^{(1)}[I(s)]$.

In the tail regions of a monopole, the electric field is a solution of (3.19); that is, $F = F(\chi; s)$ with $\chi = (y - Y(s))/\epsilon$ and

$$(4.10) \quad [v(F) - V(E_+, E_-)] \frac{\partial F}{\partial \chi} = I(s) - v(F).$$

When $I(s) < V(E_+, E_-)$ (resp., $I(s) > V(E_+, E_-)$), E_- (resp., E_+) is a function of E_+ (resp., E_-) given by $V(E_+, E_-) = v(E_-) \equiv U(E_+)$ (resp., $V(E_+, E_-) = v(E_+) \equiv W(E_-)$), and (4.10) should be solved for $\chi < 0$ (resp., $\chi > 0$) with the boundary condition $F(0-) = E_-$ (resp., $F(0+) = E_+$). Obviously F matches the value of the outer solution, $E^{(k)}[I(s)]$, as we leave the tail region, $\chi \rightarrow -\infty$ ($k = 1, 2$) or $\chi \rightarrow +\infty$ ($k = 2, 3$).

4.3. Putting the pieces together. We shall start at a time where there is only one shock wave on the SL, the current is I_F (see Figure 4), and the electric field is a shock wave joining spatially uniform regions with $E_- = E^{(1)}(I_F)$, $E_+ = E^{(3)}(I_F)$. At time $s = 0$, the shock wave is located at $y = Y_F = [E^{(3)}(I_F) - \phi] / [E^{(3)}(I_F) - E^{(1)}(I_F)]$ according to the bias condition (4.3). For $s > 0$, the shock ($E_-, 1/V$) is at the upper boundary of the domain of $E_+ = \mathcal{F}(E_-, u)$ (see the Introduction), so that $v(E_+) = V(E_+, E_-) \equiv W(E_-)$, $I < 1$, and a monopole with a rigidly moving right tail is formed. Let $y = Y(s)$ be the shock position. Then the outer field profile is

$$(4.11) \quad \begin{aligned} E(y, s) &= E^{(1)}(I(s)) & \text{if} & \quad 0 < y < Y(s), \\ E(y, s) &= E^{(3)}(I(s)) & \text{if} & \quad Y(s) < y < 1. \end{aligned}$$

The bias condition (4.3) determines $Y(s)$ as a function of $I(s)$:

$$(4.12) \quad Y = \frac{E^{(3)}(I) - \phi}{E^{(3)}(I) - E^{(1)}(I)}.$$

Inserting (4.12) into (4.7) we find the following autonomous equation for the current density:

$$(4.13) \quad \frac{dI}{ds} = \frac{(E^{(3)} - E^{(1)})^2 v'_1 W_1}{E^{(3)} - \phi + (\phi - E^{(1)}) v'_1 / v'_3} \geq 0,$$

where $v'_j = v'(E^{(j)})$, and $W_j = W(E^{(j)})$, $j = 1, 2, 3$. To obtain (4.13) we have used

$$\frac{dE^{(n)}(I)}{ds} = \frac{1}{v'(E^{(n)}(I))} \frac{dI}{ds}, \quad n = 1, 3,$$

which follows from time differentiation of (4.5) with $E = E^{(n)}(I)$. Equation (4.13) explicitly displays the quasi-steady growth of the current during this stage of the

oscillation. The solution $I(s)$ of (4.13) reaches 1 at a time $s = s_1$ which is numerically calculated. As we approach this time, $E^{(1)}(I) \sim 1 - [2(1 - I)/|v''(1)|]^{1/2}$, and the solution of (4.13) becomes

$$(4.14) \quad I \sim 1 - \frac{|v''(1)|}{2} [a(s_1 - s)]^2,$$

$$(4.15) \quad a = \frac{[E^{(3)}(1) - 1]^2 W(1)}{E^{(3)}(1) - \phi}.$$

The corresponding outer electric field profile is

$$(4.16) \quad \begin{aligned} E(y, s_1) &= 1 && \text{if } 0 < y < Y(s_1), \\ E(y, s_1) &= E^{(3)}(1) && \text{if } Y(s_1) < y < 1, \end{aligned}$$

with

$$(4.17) \quad Y(s_1) = \frac{E^{(3)}(1) - \phi}{E^{(3)}(1) - 1}.$$

Obviously after this instant our approximations break down. What happens then?

We shall see below that at $s = s_M$, $s_M - s_1 = O(\sqrt{\epsilon})$, I reaches a maximum and then decreases, while the field to the left of the monopole, $E_L = E_-$, increases linearly with time, and the field to the right of the monopole, $E_R = E^{(3)}(I)$, decreases. When I surpasses 1, E_L can no longer be approximated by $E^{(1)}(I)$. In a short time interval about $s = s_M$, E_L and I are close to 1, and the difference $I - v(E_L)$ eventually acquires a positive value of the same order as the time derivative $\epsilon dE_L/ds = O(\epsilon)$. Then $I - 1 = O(\epsilon)$, $E_L - 1 = O(\epsilon^{1/2})$, which happens in a time scale $s - s_M = O(\epsilon^{1/2})$. We thus make the ansatz

$$(4.18) \quad \hat{s} = \frac{s - s_M}{\epsilon^{1/2}},$$

$$(4.19) \quad I \sim 1 + \epsilon \hat{I}(\hat{s}),$$

$$(4.20) \quad E_L - 1 \sim \epsilon^{1/2} \hat{E}_L(\hat{s}), \quad E_R - E^{(3)}(1) \sim \epsilon \hat{E}_R(\hat{s}).$$

In the time scale (4.18), the shock speed is $O(\epsilon^{1/2})$,

$$(4.21) \quad \frac{dY}{d\hat{s}} = \epsilon^{1/2} W(1) + O(\epsilon),$$

so that

$$(4.22) \quad Y(\hat{s}) = Y(s_M) + \epsilon^{1/2} W(1) \hat{s} + O(\epsilon).$$

(Notice that $Y(s_M) - Y(s_1) = O(\epsilon)$.) Inserting the field profile (4.20) and the time scale (4.18) into (4.2), we get

$$(4.23) \quad \frac{d\hat{E}_L}{d\hat{s}} = \hat{I} - \frac{1}{2} v''(1) \hat{E}_L^2,$$

$$(4.24) \quad \epsilon^{1/2} \frac{d\hat{E}_R}{d\hat{s}} = \hat{I} - v'(E^{(3)}(1)) \hat{E}_R.$$

We therefore have

$$(4.25) \quad \hat{E}_R = \frac{\hat{I}}{v'(E^{(3)}(1))}$$

to leading order. Inserting the electric field profile and (4.22) into the bias condition (4.3), we find \hat{E}_L by equating terms of order $\epsilon^{1/2}$:

$$(4.26) \quad \hat{E}_L = \frac{(E^{(3)}(1) - 1)W(1)}{Y(s_1)} = a \hat{s},$$

where a is given by (4.15). To find \hat{I} , we substitute this result into (4.23), thereby getting

$$(4.27) \quad \hat{I} = a - \frac{|v''(1)|}{2} a^2 \hat{s}^2.$$

In outer units we therefore have

$$(4.28) \quad I \sim 1 + \epsilon a \left[1 - \frac{|v''(1)| a (s - s_M)^2}{2\epsilon} \right],$$

$$(4.29) \quad E_L \sim 1 + a (s - s_M).$$

We have chosen $E_-(s_M) = 1$, as for this value of the electric field the current density reaches its maximum. The relation between s_M and previous times for which the approximations (4.11)–(4.13) hold should be found from a matching condition. $I(s)$ takes on the value $1 - \kappa\epsilon$, $\kappa = O(1)$, at the times $s_{\kappa 1}$ and $s_{\kappa 2}$, given by

$$(4.30) \quad s_{\kappa n} = s_M + (-1)^n \sqrt{\frac{2(a + \kappa)\epsilon}{a^2|v''(1)|}},$$

with $n = 1, 2$. s_1 for which $I(s_1) = 1$ corresponds to $\kappa = 0$ in (4.30). At these times, $E_R \sim E^{(3)}(1)$ and

$$(4.31) \quad E_L(s_{\kappa n}) \sim 1 + (-1)^n \sqrt{\frac{2(a + \kappa)\epsilon}{|v''(1)|}}.$$

Notice that (4.28) and (4.14) match for any positive $\kappa = O(1)$, as their difference is

$$(4.32) \quad \sqrt{2|v''(1)|a^2(a + \kappa)\epsilon} (s - s_1) + O(\epsilon),$$

which is $O(\epsilon^{1/2}) = o(1)$ when the proper outer scales of current ($I = O(1)$) and time ($s = O(1)$) are used. We will choose appropriately the value of κ ($\kappa = 1.78$), so as to optimize the leading-order asymptotics we are describing here.

During a time interval about $s = s_M$, the time derivative of E_L is not negligible, and we have an unsteady stage during which a new shock wave is created if the excess charge c is positive. Using the current density given by equation (4.28), the new shock wave appears at $x = x_s$, $t = t_s$ (s_s, y_s in the outer variables) as obtained by solving (3.16)–(3.18). Details about the birth of the new wave are given in section 5.

After the new wave has appeared, there is a time interval where both old and new shocks (located at $y = Y$ and $y = Y_n$, respectively) coexist. The outer field profile consists of two shock waves connecting regions where the electric field is uniform:

$$(4.33) \quad \begin{aligned} E &= E_L, & 0 < y < Y_n, \\ E &= E_M, & Y_n < y < Y, \\ E &= E_R, & Y < y < L. \end{aligned}$$

The bias condition (4.3) is now

$$(4.34) \quad Y_n E_L + (Y - Y_n) E_M + (1 - Y) E_R = \phi.$$

Equation (4.5) implies that

$$(4.35) \quad E_L = E^{(1)}(I(s)), \quad E_M = E^{(2)}(I(s)), \quad E_R = E^{(3)}(I(s)).$$

The equations of motion for the monopoles are

$$(4.36) \quad \frac{dY_n}{ds} = U(E_M),$$

$$(4.37) \quad \frac{dY}{ds} = W(E_M).$$

From (4.34)–(4.37), we determine the unknowns $I(s)$, $Y_n(s)$, and $Y(s)$ as follows. The bias condition (4.34) may be rewritten as

$$(4.38) \quad Y_n = \beta - \alpha Y,$$

where

$$(4.39) \quad \alpha = \frac{E_R - E_M}{E_M - E_L}, \quad \beta = \frac{E_R - \phi}{E_M - E_L},$$

or, using (4.35),

$$(4.40) \quad \alpha = \frac{E^{(3)} - E^{(2)}}{E^{(2)} - E^{(1)}}, \quad \beta = \frac{E^{(3)} - \phi}{E^{(2)} - E^{(1)}}.$$

The three remaining unknowns Y , Y_n , and I can be determined from (4.35)–(4.39). By using these equations, we can first find Y and Y_n as functions of I and then obtain an equation for $I(s)$. Equations (4.36) and (4.37) yield

$$(4.41) \quad \frac{dY_n}{dI} = \frac{U_2}{W_2} \frac{dY}{dI}.$$

A linear equation for $Y(I)$ may be obtained from (4.38), (4.40), and (4.41):

$$(4.42) \quad \frac{dY}{dI} + \frac{\alpha' W_2}{U_2 + \alpha W_2} Y = \frac{\beta' W_2}{U_2 + \alpha W_2},$$

where α' and β' are the derivatives of α and β with respect to I .

A careful computation shows that the solution obeying $Y(1) = [E^{(3)}(1) - \phi] / [E^{(3)}(1) - 1]$ (leading-order location of the old shock wave at the time the new shock forms), and thus matches the previous stage, is

$$(4.43) \quad Y = \lim_{\gamma \rightarrow 0^+} \left\{ \int_{1-\gamma}^I \frac{W_2 \beta'}{U_2 + \alpha W_2} \exp \left[- \int_J^I \frac{\alpha' W_2}{U_2 + \alpha W_2} dr \right] dJ + \frac{E^{(3)}(1) - \phi}{E^{(3)}(1) - 1} \exp \left[- \int_{1-\gamma}^I \frac{\alpha' W_2}{U_2 + \alpha W_2} dr \right] \right\}.$$

Equation (4.43) holds as long as

$$(4.44) \quad 0 < Y \leq 1 \quad \text{and} \quad v_m \leq I < 1.$$

Taking a time derivative of the bias condition and using (4.36) and (4.37), we find

$$(4.45) \quad \frac{dI}{ds} = \frac{U_2 + \alpha W_2}{\beta' - \alpha' Y}$$

to be solved with the initial condition $I(s_s) = I_s$ (the value of the current at the shock formation time), which comes from matching with the previous stage.

The solution of this equation shows that the current decreases until one of the two conditions (4.44) breaks down. Either (i) the shock wave at $Y(s)$ reaches $y = 1$ at some time s_d , or (ii) the current $I(s)$ takes on the value v_m corresponding to the minimum electron velocity at some time s_m with $Y(s_m) < 1$. One possibility or the other is realized according to the value of the bias: let ϕ_d be the bias for which $Y = 1$ when $I = v_m$ in (4.43). For $1 \leq \phi < \phi_d$ we have possibility (i), whereas possibility (ii) is realized for $\phi > \phi_d$. In both cases, we are left after this stage with one monopole with a left tail and $E_L = E^{(1)}(I)$, and $E_R = E^{(2)}(I)$ (case (i)), or $E_R = E^{(3)}(I)$ (case (ii)), moving toward $x = L$. The current density is determined from the following equation, analogous to (4.13):

$$(4.46) \quad \frac{dI}{ds} = \frac{(E^{(k)} - E^{(1)})^2 v'_1 U_k}{E^{(k)} - \phi + (\phi - E^{(1)}) v'_1 / v'_k},$$

where $k = 2$ in case (i) or $k = 3$ in case (ii). This equation has to be solved for $s > s_d$ with the initial condition $I(s_d)$ in case (i), or for $s > s_m$ with initial data $I(s_m) = v_m$ in case (ii).

In case (i), $I'(s_d) > 0$ if

$$(4.47) \quad 1 < \phi < \left. \frac{E^{(1)} v'_1 + E^{(2)} |v'_2|}{v'_1 + |v'_2|} \right|_{s=s_d} \equiv \phi_\beta.$$

For the velocity curve we use, the bias interval (4.47) is very narrow, and the corresponding values of $I(s_d)$ are very close to 1. We may have a small-amplitude current oscillation corresponding to a supercritical Hopf bifurcation. When the bias is larger, $I'(s_d) < 0$, and I decreases until $I = v_m$ is reached and E_R becomes $E^{(3)}(I)$. From there onward, I increases and the situation is the same as in case (ii) after the fast intermediate stage. We then have a current oscillation of amplitude approximately given by $1 - v_m$. The transition from small to large-amplitude oscillation is extremely sharp, which accounts for the difficulty in observing it in simulations or in real laboratory experiments. In both cases, after some time the current density increases until the value I_F is reached, the monopole flips its tail to the right, and we have completed the asymptotic description of one period of the self-sustained oscillation. Comparison between our asymptotic solution and a numerical simulation is shown in Figure 5.

5. Birth of the new shock wave. In this section we need to solve the characteristic equations given an approximate expression for the current density, e.g., (4.28), and then calculate the shock formation time and its earliest position. These quantities can be used as initial values for the following stage of the oscillation as described in the previous section.

There are two possibilities:

- $I(t_s) \approx 1$ at the shock formation time. Then the current density may be approximated by (4.28) during the process of shock formation.

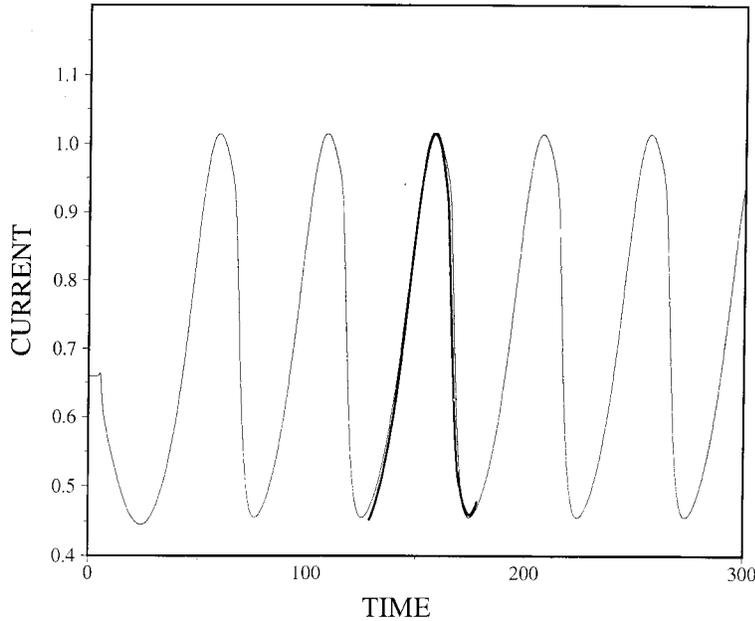


FIG. 5. Comparison between our asymptotic solution and a numerical simulation of the full model for $\phi = 1.25$, $\epsilon = 0.02$, and $c = 0.01$.

- $I(t_s) < 1$, and (4.28) ceases to hold during the last part of the process of shock formation. After the current decreases below $I = 1$, we again have a quasi-steady stage with

$$(5.1) \quad E_L \sim E^{(2)}(I), \quad E_R \sim E^{(3)}(I), \quad Y \sim \frac{E^{(3)}(I) - \phi}{E^{(3)}(I) - E^{(2)}(I)},$$

and

$$(5.2) \quad \frac{dI}{ds} \sim \frac{(E^{(3)} - E^{(2)})^2 v'_2 W_2}{E^{(3)} - \phi + (\phi - E^{(2)}) v'_2 / v'_3} \leq 0.$$

Clearly $I(s)$ and $E_R \sim E^{(3)}$ decrease while $E_- \sim E^{(2)}$ increases as the time elapses. Equation (5.2) approximates the current density from the time it has decreased below 1 until the shock formation time. If no shock wave is formed as $E^{(2)}$ approaches the value ϕ (which occurs for c sufficiently close to 0), $Y \sim 1$ according to (5.1), and the old shock wave exits at the receiving end of the SL. At this time the stationary uniform field profile $E = \phi$ is reached and maintained. These observations are in excellent agreement with the results of the numerical simulations.

For a wide interval of c , equation (4.28) describes the current density during the full shock formation stage. We will see that the shock formation time decreases as c increases for small c ; it reaches a minimum and then increases rapidly with c . Actually, (3.16) implies that the integral of $v'(E(t; \tau_s))$ has to be negative, and therefore that the field on the characteristic with $\tau = \tau_s$ needs to take values on the second branch of the $v(E)$ curve. Typically the field $E_0(\tau)$ increases with τ , it reaches a maximum, E_0^{max} , at τ_{max} , and then decreases to $E^{(1)}(I(\tau))$. We have to distinguish two cases

depending on whether E_0^{max} surpasses 1, which happens for enough small c . In fact, the critical value, \tilde{c} , for which this maximum equals 1 occurs when the current density is maximum (observe that (4.28) does not depend on c). As $I_{max} \sim 1 + \epsilon a$, then it follows from (3.9) that $\tilde{c} = \epsilon a$.

Let us consider the case $c < \tilde{c}$ in which this maximum value surpasses 1. Then the smallest time t_s for which (3.16) is satisfied is the one corresponding to the characteristic issuing from $E_0(\tau_s) = 1$. For smaller τ_s there is initially a positive contribution to the integral, leading to higher values of t_s . For larger τ_s the field along the characteristic quickly falls to $E^{(1)}(I)$ leading again to a positive contribution to the integral and therefore equation (3.16) is not satisfied. For $E_m > E(t; \tau) > 1$ the integral of the characteristic equation along the direction of increasing t is unstable. Thus, we carry out the integration of the characteristic in the direction of decreasing t , starting at $E^{(2)}(I(t_s))$ and ending at t such that $E(t; \tau_s) = 1$. The value of t_s for which equation (3.16) is satisfied gives the shock formation time and therefore the shock position. In this case, the shock formation time decreases with increasing c , because the right-hand side of (3.16) increases. We have solved this problem for $L = 50$, $c = 10^{-4}$ obtaining $t_s - t_M = 7.08$, $x_s = 7.66$, and $I(t_s) = 0.93$. This value agrees well with the result of direct numerical simulations of the model.

If $c > \tilde{c}$, the smallest time t_s for which (3.16) is satisfied is the one corresponding to the characteristic issuing from E_0^{max} ($\tau_s = \tau_{max}$). The characteristic corresponding to this value τ_s starts by giving a positive contribution to the integral until $E(t; \tau_s)$ reaches 1. Therefore, as c increases this positive contribution increases, and the shock formation time increases, which has been verified by direct numerical simulation.

Let us now find approximations to (3.16)–(3.18) with the help of our previous work on intermediate scales instead of integrating numerically the characteristic equations. Clearly we find $s_s - s_M = O(\epsilon^{1/2})$, and $y_s = O(\epsilon^{1/2})$. While the old shock wave corresponds to a monopole with a right tail moving with velocity (4.7), the new shock wave corresponds to a monopole with a left tail, moving with velocity (4.6) (see Figure 3b).

In order to estimate the shock formation time and position, we need to calculate the solution of (3.16) and (3.17) approximately. This might be quite involved, as the current density (needed to calculate the electric fields appearing on the formulas) depends on the field profiles, which should be calculated by the method of characteristics. Fortunately in the asymptotic limit $\epsilon \rightarrow 0$, the new shock wave is born during a time interval $|s - s_M| = O(\sqrt{\epsilon})$, at a distance $y_s = O(\sqrt{\epsilon})$ from $y = 0$. The current density is approximately given by the parabola (4.28), and both the equations for the field at the injecting contact and the characteristic equations are simpler. We shall give the approximate form of these equations and then insert their solutions in the exact formulas (3.16) and (3.17), whose solution yields the shock formation time.

Let us start by finding the approximate equation for the electric field at $y = 0$, (3.9). During the quasi-stationary first stage of the oscillation described by (4.11) to (4.13), the field at the SL boundary is given by the quasi-steady form of (3.9),

$$(5.3) \quad E_0(s) \sim E^{(1)} \left(\frac{I(s)}{1+c} \right),$$

until $s = s_1$. During the faster stage about s_M characterized by the scaling (4.18)–(4.20), (3.9) may be approximated by using (4.27) for \hat{I} and $E_0 - 1 = \epsilon^{1/2} \hat{E}_0$:

$$(5.4) \quad \frac{d\hat{E}_0}{d\hat{s}} = a - cL + \frac{|v''(1)|(1+c)}{2} \left(\hat{E}_0^2 - \frac{a^2 \hat{s}^2}{1+c} \right).$$

We can rewrite this equation so as to eliminate all parameters but one:

$$(5.5) \quad \frac{de_0}{d\hat{\sigma}} = \mu + e_0^2 - \hat{\sigma}^2,$$

$$(5.6) \quad \mu = \left(1 - \frac{c}{a\epsilon}\right) \sqrt{1+c},$$

$$(5.7) \quad e_0 = \frac{|v''(1)|^{1/2} (1+c)^{3/4}}{\sqrt{2a}} \hat{E}_0,$$

$$(5.8) \quad \hat{\sigma} = \frac{(|v''(1)| a)^{1/2} (1+c)^{1/4} \hat{s}}{\sqrt{2}}.$$

This equation should be solved with the initial condition

$$(5.9) \quad E_0(s_{\kappa 1}) = E^{(1)} \left(\frac{1 - \kappa\epsilon}{1+c} \right),$$

which follows from (5.3) when the current $I(s_{\kappa 1}) = 1 - \kappa\epsilon$ (for s in the overlapping region) is used (see (4.30)). If $c = O(\epsilon)$, we may solve (5.9) to leading order within the scaling (5.7)–(5.8):

$$(5.10) \quad e_0(-\sqrt{1+\kappa/a}) = -\sqrt{\frac{\kappa+c/\epsilon}{a}}.$$

A phase plane study of (5.5) indicates that E_0 increases, reaches a maximum, and then decreases. There are several cases worth consideration according to the values of the parameter μ (Figure 6). If $c < a\epsilon$, E_0 surpasses 1 (Figure 6a). In this case we need to solve (5.5) in order to find the initial condition for the characteristic equations (5.5) with $\mu = 1$. For smaller μ 's, we may still use (5.3) to approximate E_0 . In either case the shock formation time will be obtained by solving the characteristic equations with an initial condition given by the solution of (5.5) or by (5.3).

We now find the approximate form of the characteristic equations. In the scaling (4.18)–(4.20) they become

$$(5.11) \quad \frac{d\hat{E}}{d\hat{s}} = a + \frac{|v''(1)|}{2} (\hat{E}^2 - a^2 \hat{s}^2).$$

By redefining the variables in this equation, we can rewrite it as

$$(5.12) \quad \frac{de_1}{d\sigma} = 1 + e_1^2 - \sigma^2,$$

$$(5.13) \quad e_1 = \sqrt{\frac{|v''(1)|}{2a}} \hat{E}_0,$$

$$(5.14) \quad \sigma = \sqrt{\frac{a|v''(1)|}{2}} \hat{s}.$$

Notice that $\sigma = (1+c)^{-1/4} \hat{\sigma}$ by (5.8). When σ takes on this value, the field on the characteristic is equal to the boundary field E_0 . In scaled variables, the characteristic is parametrized by the value $\hat{\sigma}$ such that when $\sigma = (1+c)^{-1/4} \hat{\sigma}$, $y = 0$ and

$$(5.15) \quad e_1 \left(\frac{\hat{\sigma}}{(1+c)^{1/4}}; \frac{\hat{\sigma}}{(1+c)^{1/4}} \right) = (1+c)^{-3/4} e_0(\hat{\sigma}).$$

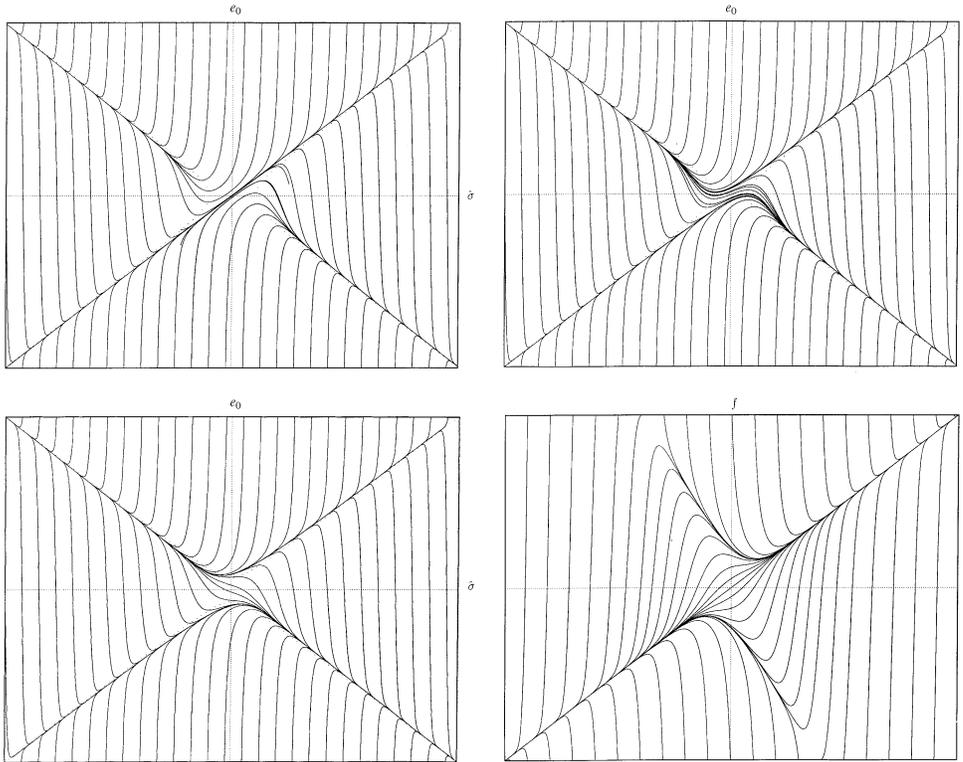


FIG. 6. Phase plane study of (5.5) corresponding to the field at $x = 0$ during the stage of shock birth. (a) $\mu = 1$, which corresponds to the electric field on the characteristics that emanate from $x = 0$. (b) $\mu = 0.5$. (c) $\mu = -0.5$. (d) Phase plane describing the death of a shock wave when $I \approx v_m$. It corresponds to (6.17) with $\delta = 0.3$.

The general solution of (5.12) is

$$(5.16) \quad e_1(\sigma; \sigma_\tau) = \sigma - \frac{1}{\int_{\sigma_0}^{\sigma} \exp(-\sigma^2 + s^2) ds},$$

for $\sigma > \sigma_0$ ($e_1 \rightarrow -\infty$ as $\sigma \rightarrow \sigma_0+$), where σ_0 is a function of $\sigma_\tau = \hat{\sigma}/(1+c)^{1/4}$ coming from the initial condition (5.15).

Inserting (5.16) in (3.16) and (3.17), we find

$$(5.17) \quad \frac{1+c}{2} \ln \left(1 + \frac{1}{c} \right) = \frac{\sigma_s^2 - \sigma_\tau^2}{2} + \ln \frac{\int_{\sigma_0}^{\sigma_s} \exp(s^2 - \sigma_s^2) ds}{\int_{\sigma_0}^{\sigma_\tau} \exp(s^2 - \sigma_\tau^2) ds},$$

$$(5.18) \quad \frac{a\epsilon}{c\sqrt{1+c}} \left(-\sigma_\tau + \frac{1}{\int_{\sigma_0}^{\sigma_\tau} \exp(-\sigma_\tau^2 + s^2) ds} \right) = \int_{\sigma_\tau}^{\sigma_s} \left[e^{(\sigma_\tau^2 - s^2)/2} \frac{\int_{\sigma_0}^s e^{r^2} dr}{\int_{\sigma_0}^{\sigma_\tau} e^{r^2} dr} \right]^{2/(1+c)} ds.$$

Here σ_s and σ_τ correspond to t_s and τ_s in (3.16)–(3.17), respectively. Notice that σ_0 is a function of $\sigma_\tau = \hat{\sigma}/(1+c)^{1/4}$ given by (5.15). We have solved these equations numerically for a fixed ϵ and different values of c , obtaining a result consistent with

that explained earlier: the shock formation time decreases as c increases for small c ; it reaches a minimum and then increases rapidly with c .

6. Death of the monopole. We only need to consider case (ii) separately, for case (i) does not require the introduction of different scales and was already analyzed in section 4. In case (ii), an intermediate stage with the same time scales as those for the shock birth describes the death of the old shock wave. We make the ansatz

$$\begin{aligned}
 (6.1) \quad & I \sim v_m + \epsilon \hat{I}, \\
 (6.2) \quad & E_{M,R} - E_m \sim \epsilon^{1/2} \hat{E}_{M,R}, \\
 (6.3) \quad & E_L - E_m^{(1)} \sim \epsilon \hat{E}_L, \quad E_m^{(1)} = E^{(1)}(v_m), \\
 (6.4) \quad & \hat{s} = \frac{s - s_m}{\epsilon^{1/2}},
 \end{aligned}$$

where s_m is the time at which the current reaches its minimum value. Equations (4.2), (4.36), and (4.37) become

$$(6.5) \quad \frac{dY_n}{d\hat{s}} = \epsilon^{1/2} U_m + O(\epsilon),$$

$$(6.6) \quad \frac{dY}{d\hat{s}} = \epsilon^{1/2} v_m + O(\epsilon),$$

$$(6.7) \quad \frac{d\hat{E}_M}{d\hat{s}} = \hat{I} - \frac{v_m''}{2} \hat{E}_M^2 + O(\epsilon^{1/2}),$$

$$(6.8) \quad \frac{d\hat{E}_R}{d\hat{s}} = \hat{I} - \frac{v_m''}{2} \hat{E}_R^2 + O(\epsilon^{1/2}),$$

$$(6.9) \quad \hat{I} - v'(E_m^{(1)}) \hat{E}_L = O(\epsilon^{1/2}),$$

where $U_m = U(E_m)$. Equations (4.38) and (4.39) still hold, but the approximation (4.40) does not. The solution of (6.5) is

$$(6.10) \quad Y_n(\hat{s}) = Y_n(s_m) + \epsilon^{1/2} U_m \hat{s} + O(\epsilon).$$

We now insert (4.33), (6.2), (6.3), and (6.10) into (4.38) and (4.39). The result is

$$\begin{aligned}
 (6.11) \quad & Y_n(s_m) + \epsilon^{1/2} U_m \hat{s} \sim \frac{E_m - \phi}{E_m - E_m^{(1)}} \\
 & + \epsilon^{1/2} \frac{[\hat{E}_R \delta - (\delta - 1) \hat{E}_M] (\phi - E_m^{(1)})}{(E_m - E_m^{(1)})^2},
 \end{aligned}$$

where we have defined

$$(6.12) \quad \delta = \frac{E_m - E_m^{(1)}}{\phi - E_m^{(1)}} (1 - Y_d).$$

Here Y_d is the position of the old shock wave when the current reaches v_m , given by (4.43) with $I = v_m$. Notice that $\delta \geq 0$; $\delta = 0$ implies that the monopole Y arrives at $x = L$ exactly when the current density becomes v_m . From the bias condition (6.11), we find the position of the new shock at $s = s_m$ and the relation

$$(6.13) \quad b\hat{s} = \hat{E}_R \delta - (\delta - 1) \hat{E}_M,$$

$$(6.14) \quad b = \frac{U_m (E_m - E_m^{(1)})^2}{\phi - E_m^{(1)}}.$$

Notice that $\hat{E}_M < 0 < \hat{E}_R$. Then (6.13) implies that $\delta < 1$, for otherwise we could not have $\hat{s} < 0$. We now need to solve (6.7), (6.8), and (6.13) for the unknowns \hat{E}_M , \hat{E}_R , and \hat{I} . Notice that (6.13) also holds at the end of the previous quasi-stationary stage where two monopoles coexist. There (6.7) and (6.8) with zero on the left side also hold, which gives us the following expression for the current at the end of the previous quasi-stationary stage:

$$(6.15) \quad \hat{I} = \frac{v_m''}{2} \left(\frac{b\hat{s}}{2\delta - 1} \right)^2$$

for $0 \leq \delta < 1/2$.

We now find the unknowns \hat{E}_M , \hat{E}_R , and \hat{I} . From (6.7) and (6.13) we can find \hat{I} and \hat{E}_M as functions of \hat{E}_R , which inserted into (6.8) yield

$$(6.16) \quad \frac{d\hat{E}_R}{d\hat{s}} = b - \frac{v_m''}{2(1-\delta)} (\hat{E}_R - b\hat{s}) [(1-2\delta)\hat{E}_R + b\hat{s}].$$

We can rewrite this equation so as to eliminate all parameters except δ :

$$(6.17) \quad \frac{df}{d\eta} = 1 - (f - \eta) [(1 - 2\delta) f + \eta],$$

$$(6.18) \quad f = \left(\frac{v_m''}{2(1-2\delta)} \right)^{1/2} \hat{E}_M, \quad \eta = \left(\frac{v_m''}{2(1-2\delta)} \right)^{1/2} b\hat{s}.$$

A phase plane study of (6.17) indicates that all trajectories tend to $f = \eta$ as $\eta \rightarrow \infty$, which matches with the quasi-stationary stage that occurs after the disappearance of the old shock wave at X_d (see below). This is illustrated by Figure 6d and by the exact expression

$$(6.19) \quad f(\eta) = \eta + \frac{1}{(1-2\delta) \int_{\eta_0}^{\eta} \exp[(-\eta^2 + s^2)\delta] ds},$$

where η_0 is a constant. Of all these trajectories, the ones that match the adiabatic stage before the old shock dies are those that follow $f = -\eta/(1-2\delta)$ and experience a fast transition to $f = \eta$. When $f = -\eta/(1-2\delta)$, the current matches (6.15). Assume that the fast transition takes place at $\eta = \eta_1 \gg 1$. An approximate expression for $f(\eta)$ may be found letting $f = -\tilde{f}\eta_1/(1-2\delta)$, and $\eta = \eta_1 + \eta'$, with $1 \ll \eta' \ll \eta_1$. Inserting this ansatz in (6.19), we find

$$(6.20) \quad \frac{d\tilde{f}}{d\eta'} = -\eta_1 (\tilde{f} + 1 - 2\delta) (1 - \tilde{f}) + O\left(\frac{1}{\eta_1}\right),$$

whose solution yields

$$(6.21) \quad f(\eta) \approx -\frac{\eta_1}{1-2\delta} \left(1 - \frac{2(1-\delta)}{1 + z e^{-2(1-\delta)\eta_1\eta'}} \right),$$

where z is a constant. After the fast transition ($\eta' \rightarrow \infty$), both \hat{E}_M and \hat{E}_R become $b\hat{s}$, the old shock dies, and the current becomes

$$(6.22) \quad I \sim v_m + \epsilon b + \frac{v_m''}{2} b^2 (s - s_m)^2.$$

It is interesting to find out when the current I reaches the value v_m . In terms of the variables η and f , \hat{I} may be written as

$$(6.23) \quad \hat{I} = \frac{(\eta + f\delta)^2 - 1 - \frac{df}{d\eta}\delta}{1 - \delta}.$$

Notice that $\hat{I} = 0$ if $f = -\eta/\delta$. Then the current reaches $I = v_m$ ($\hat{I} = 0$) if the slope of the line $f = -\eta/\delta$ is larger than the slope of $f(\eta)$ as $\eta \rightarrow -\infty$; i.e., $1/\delta > 1/(1-2\delta)$. This implies $0 \leq \delta < 1/3$, which occurs for biases $\phi_d < \phi < \phi_\delta$. When the bias is larger, $1/3 < \delta < 1/2$, and the minimum of the current is larger than v_m .

7. Concluding remarks. We have developed an asymptotic theory for the continuum limit of a discrete drift model of doped SLs. Our theory is in excellent quantitative agreement with numerical simulations of the discrete model for long enough SLs. Our asymptotic analysis of the continuum equations indicates that they have a stable time-periodic solution for an appropriate bias. That this is indeed so remains an important open mathematical problem. The time-periodic oscillation is due to repeated creation and propagation of traveling monopole wavefronts formed by a shock wave and an attached tail region moving at the same velocity as the shock. The study of the shock-wave dynamics allows us to reduce the complexity of the problem by decomposing it into “coherent” structures and analyzing their simpler reduced dynamics. This decomposition should in principle yield a full explanation of the classical chaos observed numerically when an appropriate harmonic forcing is added to the bias [9].

The present phenomena are related to the well-known Gunn instability in bulk semiconductors [26, 24, 13, 2, 7]. The main mathematical difference is that the traveling waves responsible for the usual Gunn effect are solitary waves of the electric field (charge dipoles), while in the present case they are monotone wavefronts of the electric field (charge monopoles). We remark that the first numerical observation of a “Gunn-like” instability (in a drift-diffusion model with different boundary conditions from ours) mediated by monopoles is due to Kroemer [19]. An incomplete asymptotic study of the Kroemer drift-diffusion model valid for particular electron velocities was performed in [13]. The fact that many different models (e.g., “slow” Gunn effect in ultrapure Germanium [8, 3, 5, 10]) present the Gunn instability poses the problem of characterizing the model features that produce the Gunn effect, as precisely as possible.

Other open problems presently being considered include explaining how well the asymptotic solution approximates the solution of the discrete equations and how well these results compare with experiments [15, 16, 20]. To this end, it is important to extend the asymptotic analysis to a more complete model of SLs under photoexcitation [4, 6]. Finally, a careful derivation of the discrete drift model from a fully quantum-mechanical setting would be most desirable. None of the presently known derivations is satisfactory.

Appendix A. Brief derivation of the continuum model from the discrete model. An SL is a periodic succession of alternating long (for simplicity) slabs of two semiconductors (GaAs and AlAs in [16, 20]). Since the energy bandgap is different for the two semiconductors, the SL may be thought of as a periodic succession of potential “barriers” and “valleys.” Along the growth direction of a finite SL, we find N periods formed by a barrier and a valley with a typical length of tens of nanometers. The lateral dimension may be one or ten thousand times larger, so that transport phenomena along the growth dimension may be considered to be one dimensional. In the simplest case of an n -doped N -period SL without laser illumination, the discrete drift model consists of the following system of equations [6, 4]:

$$(A.1) \quad \tilde{E}_j - \tilde{E}_{j-1} = \frac{e\tilde{l}}{\epsilon} (\tilde{n}_j - \tilde{N}_D),$$

$$(A.2) \quad \epsilon \frac{d\tilde{E}_j}{d\tilde{t}} + e \tilde{v}(\tilde{E}_j) \tilde{n}_j = \tilde{J},$$

$$(A.3) \quad \frac{1}{N} \sum_{j=1}^N \tilde{E}_j = \frac{\tilde{\Phi}}{N\tilde{l}},$$

where $j = 1, \dots, N$. In this model (A.1) and (A.2) are, respectively, the one-dimensional Poisson equation (averaged over one SL period) and Ampère's law for the electric field $\tilde{E}_j(\tilde{t})$ and electron density $\tilde{n}_j(\tilde{t})$ at the site j and for the total current density $\tilde{J}(\tilde{t})$. In these equations, the positive constants ϵ , \tilde{N}_D , \tilde{l} , and e are the average permittivity, average donor concentration, SL period, and the absolute value of the charge of the electron. $\tilde{v}(\tilde{E})$ is an effective electron velocity to be specified later. Equation (A.3) establishes that the average electric field is given by the dc -voltage bias $\tilde{\Phi}$. Notice that there are $2N+2$ unknowns: $\tilde{E}_0, \tilde{E}_1, \dots, \tilde{E}_N, \tilde{n}_1, \dots, \tilde{n}_N, \tilde{J}$ and $2N+1$ equations so that we need to specify one boundary condition for \tilde{E}_0 plus an appropriate initial profile $\tilde{E}_j(0)$. The boundary condition for \tilde{E}_0 (the average electric field *before* the SL) can be fixed by specifying the electron density at the first site, \tilde{n}_1 , according to (A.1). In typical experiments the region before the SL has an excess of electrons due to a stronger n-doping there than in the SL [16, 20]. Thus it is plausible assuming that there is an excess number of electrons at the first SL period measured by a dimensionless parameter c :

$$(A.4) \quad \tilde{E}_1(\tilde{t}) - \tilde{E}_0(\tilde{t}) = \frac{ce\tilde{l}\tilde{N}_D}{\epsilon}.$$

c has to be quite small because it is known that a steady uniform-electric-field profile is observed at low laser illumination in undoped SL [20, 4]. If we adopt (A.4) with $0 < c \ll 1$ as our boundary condition, a steady almost uniform electric field profile is clearly a possible solution of (A.1)–(A.3).

The only function not specified so far is the electron velocity $\tilde{v}(\tilde{E})$. This function is used to model sequential resonant tunneling (SRT) [6] in the SL, which is the main charge transport mechanism for the high electric fields. The velocity curve can be derived from experiments [6] or from simple one-dimensional quantum-mechanical calculations of resonant tunneling, as was done by Prengel, Wacker, and Schöll [25, 14]. For our analysis, the only important characteristic of the velocity curve is that it has to have a local maximum and a local minimum and therefore a region in which the velocity decreases with increasing field. In our analysis we will use the curve depicted in the inset of Figure 1a.

It is convenient to render equations (A.1)–(A.4) dimensionless by adopting as the units of electric field and velocity the values at the first positive maximum of the velocity curve $\tilde{v}(\tilde{E})$, \tilde{E}_M , and \tilde{v}_M (about 10^5 V/cm and 427 cm/s, respectively, for the sample of [16]). We set

$$(A.5) \quad E_j = \frac{\tilde{E}_j}{\tilde{E}_M}, \quad n_j = \frac{\tilde{n}_j}{\tilde{N}_D}, \quad I = \frac{\tilde{J}}{e\tilde{N}_D\tilde{v}_M},$$

$$t = \frac{\tilde{v}_M\nu\tilde{t}}{\tilde{l}}, \quad \phi = \frac{\tilde{\Phi}}{N\tilde{E}_M\tilde{l}},$$

where the dimensionless parameter ν , defined as

$$(A.6) \quad \nu = \frac{\tilde{N}_D e \tilde{l}}{\epsilon \tilde{E}_M},$$

is about 0.1 for the SL used in the experiments [16]. Then the dimensionless equations of the model are

$$(A.7) \quad E_j - E_{j-1} = \nu (n_j - 1),$$

$$(A.8) \quad \frac{dE_j}{dt} + v(E_j) n_j = I,$$

$$(A.9) \quad \frac{1}{N} \sum_{j=1}^N E_j = \phi,$$

$$(A.10) \quad E_1 - E_0 = \nu c, \quad c \ll 1.$$

Here $v(E) = \tilde{v}(\tilde{E})/\tilde{v}_M$, and ϕ is a dimensionless control parameter (the *dc* bias), whereas ν , c , and N are fixed for each SL. Equations (A.7) and (A.8) are to be solved with initial conditions for the fields $E_j(0)$, compatible with the bias (A.9) and the boundary condition (A.10). The initial conditions for the electron density $n_j(0)$ then follow from (A.7).

In the continuum limit $\nu \rightarrow 0$, $N \rightarrow \infty$ so that

$$(A.11) \quad x = j\nu \in [0, L], \quad L = N\nu \gg 1,$$

the system of equations (A.7)–(A.10) becomes (1.1)–(1.3) after the electron density $n(x, t)$ is eliminated by means of Poisson’s equation. The hyperbolic equation (1.1) develops shock waves from initial data in finite time [2, 24]. To determine their velocity and entropy condition we have to go back to the discrete model (A.7)–(A.10) [4]. The shock wave is a field profile that moves rigidly with an average speed $V(E_+, E_-)$, so that $E_j(t) = E(j - j_s(t))$ with $E(-\infty) = E_-$, $E(+\infty) = E_+$ and $j_s(t + \Delta t) - j_s(t) \sim V(E_+, E_-) \Delta t/\nu$ for large enough Δt . $j_s(t)$ is the QW where the profile $n_j(t)$ reaches its maximum value at time t and $X(t) = \nu j_s(t)$ corresponds to the shock position in the continuum limit. Then $E_j(t + \Delta t) - E_j(t)$ is approximately given by the distance $j_s(t + \Delta t) - j_s(t)$ that the shock has advanced during Δt times the field difference $-(E_j - E_{j-1})$ at some intermediate time in $(t, t + \Delta t)$. Thus we have

$$(A.12) \quad \frac{dE_j}{dt} \sim -\frac{E_j - E_{j-1}}{\nu} V(E_+, E_-).$$

If we now sum $(E_j - E_{j-1})$ over the shock region, we obtain $E_+ - E_-$. On the other hand $n_j = O(\nu^{-1}) \gg 1$ and $I = O(1)$ in the shock region, so that (A.7), (A.8), and (A.12) yield

$$(A.13) \quad \begin{aligned} E_+ - E_- &= \sum_{j=-\infty}^{\infty} (E_j - E_{j-1}) \sim - \sum_{j=-\infty}^{\infty} \frac{\nu}{v(E_j)} \frac{dE_j}{dt} \\ &\sim V(E_+, E_-) \sum_{j=-\infty}^{\infty} \frac{E_j - E_{j-1}}{v(E_j)}. \end{aligned}$$

In the continuum limit this becomes the equal area rule (1.4)

$$\int_{E_-}^{E_+} \left(\frac{1}{v(E)} - \frac{1}{V(E_+, E_-)} \right) dE = 0.$$

To keep $n_j \geq 0$ inside the shock we must add the restrictions

$$v(E_-) \geq V(E_+, E_-) \geq v(E_+)$$

(and hence $V = v(E)$ at only one point x inside the shock). Likewise, no shock with $E_+ < E_-$ arises from realistic initial conditions with $n_j \geq 0$ [13]. Typical solutions of the equal area rule (1.4) compatible with the entropy condition (1.5) are depicted in Figure 2. Notice that we can have admissible values of E_- and E_+ belonging to equal or different branches of $1/v(E)$. However, for E_- and E_+ to be on the same branch of $1/v(E)$ they must belong to the second branch, with $v'(E) < 0$.

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